

ON Semiconductor®

NC7S00

TinyLogic® HS 2-Input NAND Gate

General Description

The NC7S00 is a single 2-Input high performance CMOS NAND Gate. Advanced Silicon Gate CMOS fabrication assures high speed and low power circuit operation over a broad V_{CC} range. ESD protection diodes inherently guard both inputs and output with respect to the V_{CC} and GND rails. Three stages of gain between inputs and output assures high noise immunity and reduced sensitivity to input edge rate.

Features

- Space saving SOT23 or SC70 5-lead package
- Ultra small MicroPak™ leadless package
- High speed: t_{PD} 3.5 ns typ
- \blacksquare Low Quiescent Power: $I_{CC} < 1~\mu\text{A}$
- \blacksquare Balanced Output Drive: 2 mA I $_{\rm OL}$, -2 mA I $_{\rm OH}$
- Broad V_{CC} Operating Range: 2V–6V
- Balanced Propagation Delays
- Specified for 3V operation

Ordering Code:

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N	Order Number	der Number Package Product Code Package Description		Supplied As					
	Order Number	Number	Top Mark	Fackage Description	Supplied As				
	NC7S00M5X	MA05B	7S00	5-Lead SOT23, JEDEC MO-178, 1.6mm	3k Units on Tape and Reel				
	NC7S00P5X	MAA05A	S00	5-Lead SC70, EIAJ SC-88a, 1.25mm Wide	3k Units on Tape and Reel				
	NC7S00L6X	MAC06A	A3	6-Lead MicroPak, 1.0mm Wide	5k Units on Tape and Reel				

Logic Symbol



Pin Descriptions

Pin Names	Description
A, B	Input
Y	Output
NC	No Connect

Function Table

$$Y = \overline{AB}$$

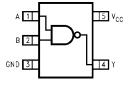
Inp	Output	
Α	В	Y
L	L	Н
L	Н	Н
Н	L	Н
Н	Н	L

H = HIGH Logic Level

 $\mathsf{L} = \mathsf{LOW} \; \mathsf{Logic} \; \mathsf{Level}$

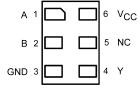
Connection Diagrams

Pin Assignments for SC70 and SOT23



(Top View)

Pad Assignments for MicroPak



(Top Thru View)

Absolute Maximum Ratings(Note 1)

Recommended Operating Conditions (Note 2)

-0.5V to +7.0V	Cona
	Supply V
−20 mA	Input Vol
+20 mA	Output V
$-0.5V$ to $V_{CC} + 0.5V$	Operatin
	Input Ris
−20 mA	V _{CC} @
+20 mA	V _{CC} @
–0.5V to V_{CC}^{+} 0.5V	V _{CC} @
	V _{CC} @
	-20 mA $+20 \text{ mA}$ $-0.5\text{V to V}_{\text{CC}} + 0.5\text{V}$ -20 mA $+20 \text{ mA}$

or Sink Current (I_{OUT}) ±12.5 mA

DC V_{CC} or Ground Current per Output Pin (I_{CC} or I_{GND})

±25 mA Storage Temperature (T_{STG}) -65°C to +150°C Junction Temperature (T_J) 150°C

Lead Temperature (T_L);

(Soldering, 10 seconds)

Power Dissipation (P_D) @ +85°C

SOT23-5 200 mW SC70-5 150 mW

Voltage (V_{CC}) 2.0V-6.0V oltage (V_{IN}) $0V-V_{CC}$ $0V-V_{CC}$ Voltage (V_{OUT}) -40°C to +85°C ng Temperature (T_A) se and Fall Time (t_r, t_f) @ 2.0V 0-1000 ns @ 3.0V 0-750 ns @ 4.5V 0-500 ns @ 6.0V 0-400 ns Thermal Resistance (θ_{JA}) SOT23-5 300°C/W

425°C/W SC70-5 Note 1: Absolute maximum ratings are those values beyond which damage to the device may occur. The databook specifications should be met, with-

out exception, to ensure that the system design is reliable over its power supply, temperature, and output/input loading variables. ON Semiconductor does not recommend operation of circuits outside the

Note 2: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	V _{CC}	V_{CC} $T_A = +25^{\circ}C$		$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units	Conditions	
Symbol	i didilictei	(V)	Min	Тур	Max	Min	Max	Oille	Conditions
V _{IH}	HIGH Level Input Voltage	2.0	1.50			1.50		V	
		3.0 - 6.0	0.7 V _{CC}			0.7V _{CC}		v	
V _{IL}	LOW Level Input Voltage	2.0			0.50		0.50	V	
		3.0 - 6.0			$0.3V_{CC}$		$0.3\mathrm{V}_{\mathrm{CC}}$	v	
V _{OH}	HIGH Level Output Voltage	2.0	1.90	2.0		1.90			
		3.0	2.90	3.0		2.90		V	$I_{OH} = -20 \ \mu A$ $V_{IN} = V_{IL}$
		4.5	4.40	4.5		4.40		v	$V_{IN} = V_{IL}$
		6.0	5.90	6.0		5.90			
									$V_{IN} = V_{IL}$
		3.0	2.68	2.85		2.63		V	$I_{OH} = -1.3 \text{ mA}$
		4.5	4.18	4.35		4.13		v	$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.85		5.63			$I_{OH} = -2.6 \text{ mA}$
V _{OL}	LOW Level Output Voltage	2.0		0.0	0.10		0.10		
		3.0		0.0	0.10		0.10	V	$I_{OL} = 20 \mu A$ $V_{IN} = V_{IH}$
		4.5		0.0	0.10		0.10	•	$V_{IN} = V_{IH}$
		6.0		0.0	0.10		0.10		
									$V_{IN} = V_{IH}$
		3.0		0.1	0.26		0.33	V	$I_{OL} = 1.3 \text{ mA}$
		4.5		0.1	0.26		0.33	v	$I_{OL} = 2 \text{ mA}$
		6.0		0.1	0.26		0.33		$I_{OL} = 2.6 \text{ mA}$
I _{IN}	Input Leakage Current	6.0			±0.1		±1.0	μΑ	$V_{IN} = V_{CC}$, GND
I _{CC}	Quiescent Supply Current	6.0			1.0		10.0	μΑ	$V_{IN} = V_{CC}$, GND

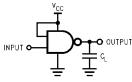
260°C

AC Electrical Characteristics

Symbol	Parameter	v _{cc}	V_{CC} $T_A = +25^{\circ}C$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units	Conditions	Figure	
Cymbol	r drumeter	(V)	Min	Тур	Max	Min	Max	Omis	Conditions	Number
t _{PLH} ,	Propagation Delay	5.0		3.5	15			ns	$C_{L} = 15 \text{ pF}$	
t _{PHL}		2.0		19	100		125	ns	C _L = 50 pF	l
		3.0		10.5	27		35			Figures 1, 3
		4.5		7.5	20		25			
				6.5	17		21			
t _{TLH} ,	Output Transition Time	5.0		3.0	10			ns	C _L = 15 pF	
t_{THL}		2.0		25	125		155			Figures 1, 3
		3.0		16	35		45		C F0 *F	
		4.5		11	25		31	ns	$C_L = 50 pF$	
		6.0		9	21		26			
C _{IN}	Input Capacitance	Open		2	10		10	pF		
C _{PD}	Power Dissipation Capacitance	5.0		6				pF	(Note 3)	Figure 2

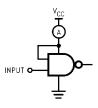
Note 3: C_{PD} is defined as the value of the internal equivalent capacitance which is derived from dynamic operating current consumption (I_{CCD}) at no output loading and operating at 50% duty cycle. (See Figure 2.) C_{PD} is related to I_{CCD} dynamic operating current by the expression:
I_{CCD} = (C_{PD}) (V_{CC}) (f_{IN}) + (I_{CC}static).

AC Loading and Waveforms



 C_L includes load and stray capacitance Input PRR = 1.0 MHz, $t_{\rm w}$ = 500 ns

FIGURE 1. AC Test Circuit



Input = AC Waveform;

PRR = variable; Duty Cycle = 50%

FIGURE 2. I_{CCD} Test Circuit

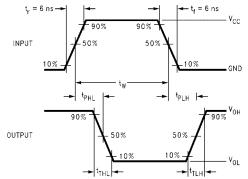


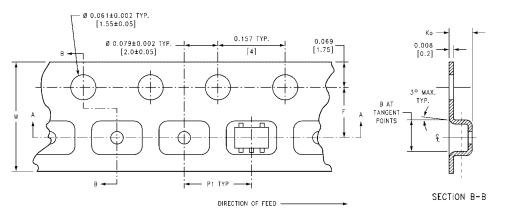
FIGURE 3. AC Waveforms

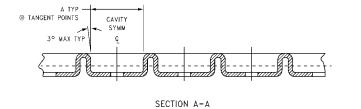
Tape and Reel Specification

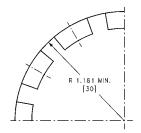
TAPE FORMAT for SC70 and SOT23

Package	Tape	Number	Cavity	Cover Tape	
Designator	Section	Cavities	Status	Status	
	Leader (Start End)	125 (typ)	Empty	Sealed	
M5X, P5X	Carrier	3000	Filled	Sealed	
	Trailer (Hub End)	75 (typ)	Empty	Sealed	

TAPE DIMENSIONS inches (millimeters)



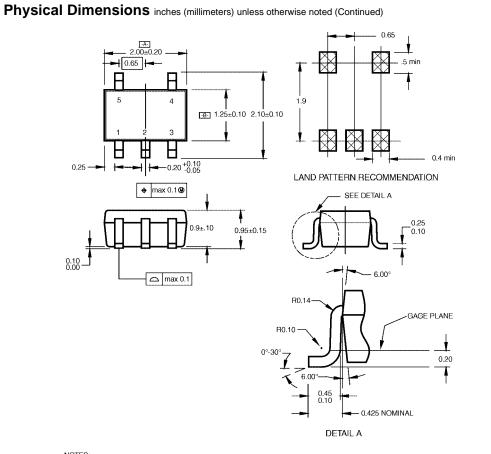




BEND RADIUS NOT TO SCALE

Package	Tape Size	DIM A	DIM B	DIM F	DIM K _o	DIM P1	DIM W
SC70-5	8 mm	0.093	0.096	0.138 ±0.004	0.053 ±0.004	0.157	0.315 ±0.004
3070-5	0 111111	(2.35)	(2.45)	(3.5 ±0.10)	(1.35 ±0.10)	(4)	(8 ±0.1)
SOT23-5	8 mm	0.130	0.130	0.138 ±0.002	0.055 ±0.004	0.157	0.315 ±0.012
30123-3	O IIIIII	(3.3)	(3.3)	(3.5 ±0.05)	(1.4 ±0.11)	(4)	(8 ±0.3)

Tape and Reel Specification (Continued) TAPE FORMAT for MicroPak Package Tape Number Cavity Cover Tape Designator Section Cavities Status Status Leader (Start End) 125 (typ) Empty Sealed L6X Carrier 5000 Filled Sealed Trailer (Hub End) 75 (typ) **Empty** Sealed 2.00-1.75±0.10 В 8.00 ^{+0.30} -0.10 3.50±0.05 1.15±0.05 **-** → В◄ -ø 0.50 ±0.05 SECTION B-B DIRECTION OF FEED SCALE:10X 0.254±0.020 Г 0.70±0.05 SECTION A-A SCALE:10X **REEL DIMENSIONS** inches (millimeters) TAPE SLOT DETAIL X **DETAIL X** SCALE: 3X Tape Α В С D N W1 W2 W3 Size 0.795 2.165 0.331 +0.059/-0.000 0.567 W1 +0.078/-0.039 0.059 0.512 8 mm (177.8)(1.50)(13.00)(20.20)(55.00)(8.40 +1.50/-0.00) (14.40)(W1 +2.00/-1.00)



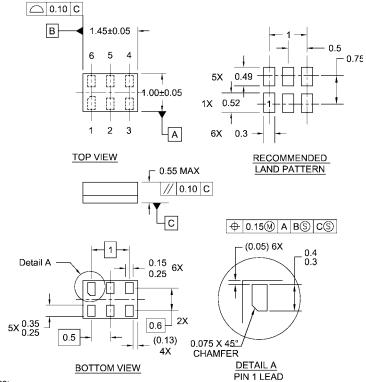
NOTES:

A. CONFORMS TO EIAJ REGISTERED OUTLINE DRAWING SC88A. B. DIMENSIONS DO NOT INCLUDE BURRS OR MOLD FLASH. C. DIMENSIONS ARE IN MILLIMETERS.

MAA05ARevC

5-Lead SC70, EIAJ SC-88a, 1.25mm Wide Package Number MAA05A

Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



Notes:

- 1. JEDEC PACKAGE REGISTRATION IS ANTICIPATED 2. DIMENSIONS ARE IN MILLIMETERS 3. DRAWING CONFORMS TO ASME Y14.5M-1994

MAC06ARevB

6-Lead MicroPak, 1.0mm Wide Package Number MAC06A

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